## Effects of Continuous Chalcogen Substitution on Energetics and Electronic Properties of WSSe

## Susumu Okada

Yanlin Gao, Mina Maruyama Department of Physics, University of Tsukuba, 1-1-1 Tennodai, Tsukuba, Japan sokada@comas-tsukuba.jp

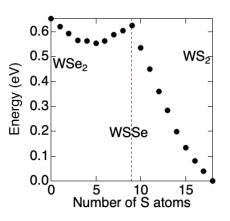
Transition metal dichalcogenides (TMDs) can form in-plane and out-of-plane heterostructures whose physical properties are sensitive to their morphologies [1]. Among such heterostructures, Janus TMDs are now keeping a premier position in the field of atomic layer materials because they have unique heterostructure across their atomic layers: A transition metal layer is sandwiched by different chalcogen atomic layers leading to peculiar electronic structure owing to the internal electric field [2]. Experiments reported that Janus TMDs can be obtained by sulfurization or selenization on MSe<sub>2</sub> or MS<sub>2</sub>, where M is a transition metal, respectively [3]. However, the detailed mechanism of Janus TMD formation is still unclear. Thus, this work aims to clarify the formation mechanism of Janus WSSe by conducting the first-principles total energy calculations based on the density functional theory with the effective screening medium method.

Our calculations on  $WS_xSe_{(1-x)}$  demonstrated that  $WS_2$  is the most stable structure. In contrast, Janus WSSe is the least stable structure. In addition, during the sulfurization from  $WSe_2$  to WSSe,  $WS_{0.555}Se_{1.444}$  is the metastable structure possessing the lowest total energy because of the competition between the energy cost of dipole energy and the energy gain of S-W bond formation. The electronic structure of  $WS_xSe_{(1-x)}$  shows contentious change concerning sulfur concentration, inconsistent with an in-situ observation of Janus formation. Therefore, our calculations imply that contentious sulfurization is not a possible synthesis process for the Janus formation [3].

## References

- [1] M. Maruyama et al., ACS Appl. Nano Mater. 6 (2023) 5434.
- [2] Y. Gao, S. Okada, Appl. Phys. Express 16 (2003) 075004.
- [3] Y. Gao, M. Maruyama, S. Okada, Jpn. J. Appl. Phys. 63 (2024) 065001.

Figure



**Figure 1:** Relative total energy per W atom of  $WS_{(2-x)}Se_x$  as a function of the number of S atoms n.  $WSe_2$ ,  $WS_2$ , and Janus WSSe correspond to n = 0, 18, and 9, respectively. The energies are measured based on that of  $WS_2$ .

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